## 22213

21	222	2											
				Marks	Seat	No.							
15 minutes extra for each hour   Instructions - (1) All Questions are Compulsory.													
11	1511 11	errons	(1) (2)	Answer each	-		on c	on a	n ne	w	nag	e	
				Illustrate your necessary.						-			
			(4)	Figures to the	e right ind	icate fu	ll m	ark	s.				
			(5)	Assume suital	ole data, it	f necess	sary.						
			(6)	Use of Non-p Calculator is	•		etron	ic l	Pocl	ket			
			(7)	Mobile Phone Communicatio	on devices	•							
				Examination 1	Hall.						T	Ma	rks
											1		1115
1.		Attempt	any	<b><u>FIVE</u></b> of the	following	:							10
	a)	State the	typi	cal knee volta	ge values	for Si	and	Ge	dic	odes	5.		
	b)	State the	nee	d of rectifiers.	List the t	types of	f rec	tifie	ers.				
	c) Draw a symbol of PNP and NPN transistors.												
	d)	State the	outj	put voltage of	IC 7824 a	nd IC 7	906.						
	e)	Suggest	the s	uitable diode	type for v	oltage r	egul	ator	cii	rcui	t.		
	f)	Define the terms											
		i) Lin	e Re	gulation									
		ii) Loa	nd Ro	egulation									
	g)	Draw the	e syr	nbol and truth	table of l	EX-OR	gate	<b>).</b>					

2.		Attempt any THREE of the following:	12				
	a)	Describe the V-I characteristics of a P-N junction diode with proper sketch and define					
		i) Break over voltage					
		ii) Reverse breakdown voltage					
	b)	Describe the working of half wave rectifier with LC filter using neat circuit diagram					
	c)	Explain transistor as a switch with neat sketch.					
	d)	Sketch the block diagram of DC regulated power supply. State the function of each block.					
3.		Attempt any THREE of the following:	12				
	a)	Explain the functional block diagram of IC723 with neat sketch.					
	b)	Describe the working of crystal oscillator with neat diagram.					
	c)	State the various transistor configurations. State any four applications of BJT.					
	d)	Compare half-wave rectifier with full wave centre-tapped rectifier on the basis of Ripple factor, Rectifier efficiency, TUF and PIV.					
4.		Attempt any THREE of the following:	12				
	a)	State the Barkhausen criteria. Draw the circuit diagram of colpitt's oscillator.					
	b)	Draw the circuit diagram of bridge rectifier with $\pi$ filter. Draw it's input and output waveforms.					
	c)	A transistor has $I_B = 110 \mu$ A, $I_C = 2 m$ A. Calculate $\alpha$ and $\beta$ .					
	d)	Describe the construction details of light emitting diode (LED) with neat sketch. State the application of LED.					

- Marks
  - 2

- e) Figure No. 01. shows the centre tapped full wave rectifier circuit. Assume both the diodes to be ideal. Determine
  - i) DC output voltage (Vdc) and
  - ii) Peak inverse voltage (PIV) of diode

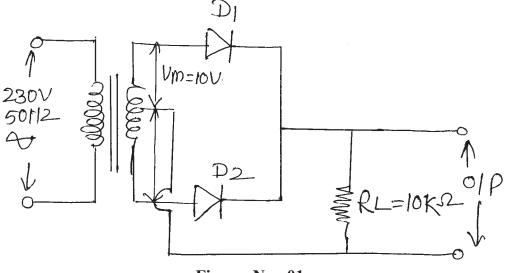


Figure No. 01.

## 5. Attempt any TWO of the following:

- a) A transistor has a typical  $\beta = 100$ . If the collector circuit is 40 mA. Determine the value of base current, emitter current and  $\alpha$ .
- b) For zener voltage regulator, if  $I_{Zmin} = 2 \text{ mA}$ ,  $I_{Zmax} = 20 \text{ mA}$ ,  $V_Z = 4.7 \text{ V}$ . Determine the range of input voltage over which output voltage remains constant.  $R_L = 1 \text{ k}\Omega$ ,  $R = 1\Omega$ ,  $Z_Z = 0\Omega$ . Refer Figure No. 02.

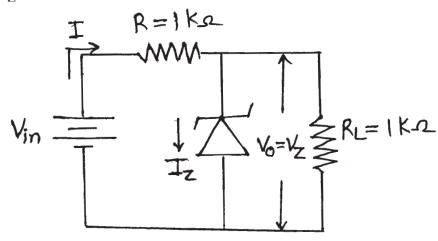


Figure No. 02.

P.T.O.

12

12

c) State the disadvantage of JK flip-flop. Explain the working of MS JK flip-flop with proper diagram.

## 6. Attempt any <u>TWO</u> of the following:

- a) Compare RC and LC oscillators. (six points)
- b) Sketch common base configuration input characteristics for two different values of  $V_{CB}$  and O/P characteristics for two different values  $I_E$ . Write the formula for input resistance and output resistance.
- c) Convert the following
  - i)  $(208)_{10} = ()_2$
  - ii)  $(AgC)_{16} = ( )_8$
  - iii)  $(247)_8 = ( )_{10}$